

KBPC6005 THRU KBPC610

SINGLE-PHASE SILICON BRIDGE RECTIFIER



REVERSE VOLTAGE: 50 to 1000 VOLTS
FORWARD CURRENT: 6.0 AMPERE

FEATURES

- Low forward voltage drop and reverse leakage
- Ideal for printed circuit board
- Plastic material has Underwriters Laboratory Flammability Classification 94V-0
- Reliable low cost construction
- High surge current capability

MECHANICAL DATA

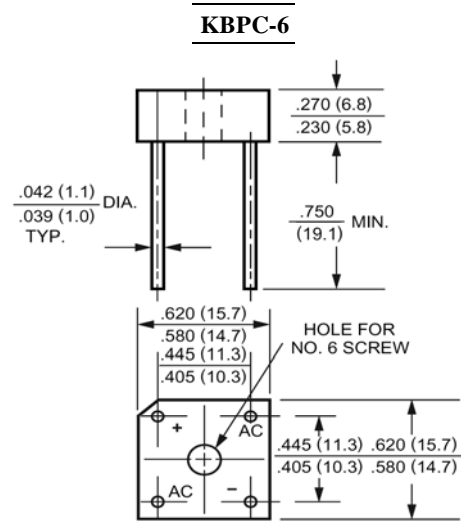
Case: Molded plastic, KBPC-6

Epoxy: UL 94V-0 rate flame retardant

Terminals: Leads solderable per MIL-STD-202, method 208 guaranteed

Mounting position: Any

Weight: 0.12ounce, 3.3gram



Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

	Symbols	KBPC6005	KBPC601	KBPC602	KBPC604	KBPC606	KBPC608	KBPC610	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Rectified Current at $T_C=50^\circ\text{C}$	$I_{(AV)}$	6.0							Amp
Peak Forward Surge Current, 8.3ms single half-sine-wave superimposed on rated load (JEDEC method)	I_{FSM}	200							Amp
Maximum Forward Voltage Drop per Element at 3.0A DC and 25°C	V_F	1.0							Volts
Maximum Reverse Current at $T_A=25^\circ\text{C}$ at Rated DC Blocking Voltage $T_A=100^\circ\text{C}$	I_R	10.0							uAmp
Typical Junction Capacitance (Note 1)	C_J	186							pF
Typical Thermal Resistance (Note 2)	$R_{\theta JA}$	22							°C/W
Typical Thermal Resistance (Note 3)	$R_{\theta JC}$	7.3							°C/W
Operating and Storage Temperature Range	T_J, T_{stg}	-55 to +125							°C

NOTES:

1- Measured at 1 MHz and applied reverse voltage of 4.0 VDC.

2- Unit mounted on 5.5 x 6.0 x 0.11" thick (14 x 15 x 0.3cm) Al. Plate

3- Unit mounted on P.C.B. at 0.375" (9.5mm) lead length with 0.5 x 0.5" (12 x 12mm) copper pads

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RATINGS AND CHARACTERISTIC CURVES

FIG.1- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT PER BRIDGE ELEMENT

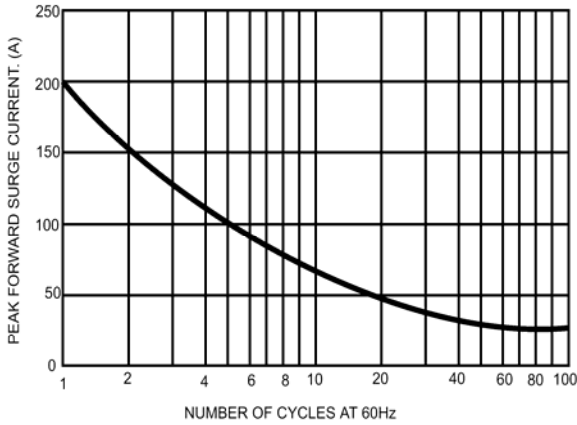


FIG.2- MAXIMUM FORWARD CURRENT DERATING CURVE

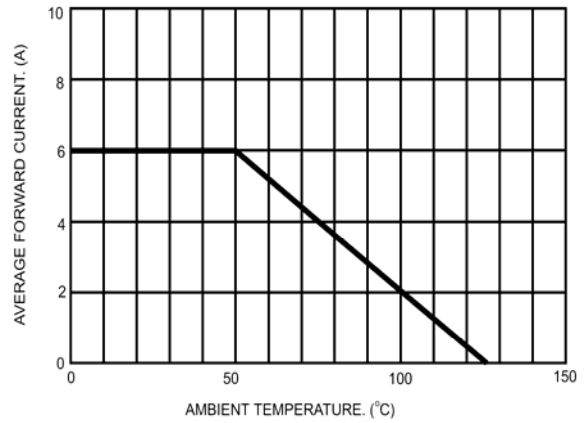


FIG.3- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS PER BRIDGE ELEMENT

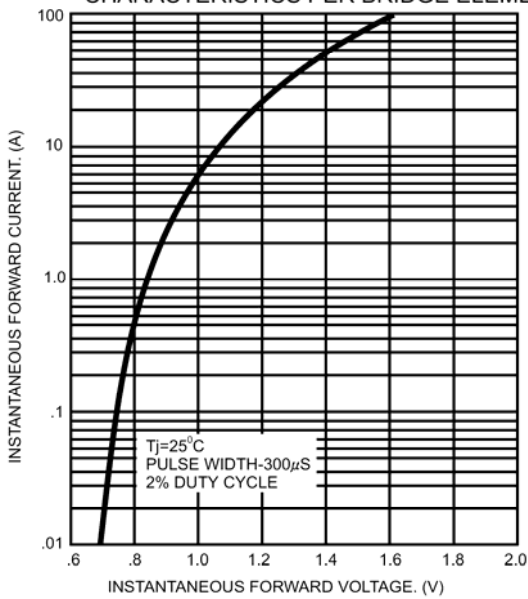


FIG.4- TYPICAL REVERSE CHARACTERISTICS PER BRIDGE ELEMENT

